

# **BGA6489**

# MMIC wideband medium power amplifier

Rev. 02 — 15 June 2009

**Product data sheet** 

# 1. Product profile

# 1.1 General description

The BGA6489 is a silicon Monolithic Microwave Integrated Circuit (MMIC) wideband medium power amplifier with internal matching circuit in a 3-pin SOT89 plastic, low thermal resistance, SMD package.

The BGA6x89 series of medium power gain blocks are resistive feedback Darlington configured amplifiers. Resistive feedback provides large bandwidth with high accuracy.

#### **CAUTION**



This device is sensitive to ElectroStatic Discharge (ESD). Therefore care should be taken during transport and handling.

#### 1.2 Features

- Broadband 50 Ω gain block
- 20 dBm output power
- SOT89 package
- Single supply voltage needed

# 1.3 Applications

- Broadband medium power gain blocks
- Small signal high linearity amplifiers
- Variable gain and high output power in combination with the BGA2031
- Cellular, PCS and CDPD
- IF/RF buffer amplifier
- Wireless data SONET
- Oscillator amplifier, final PA
- Drivers for CATV amplifier



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# 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_D$	DC device voltage	on pin 1; $I_S = 78 \text{ mA}$	-	5.1	-	V
I <sub>S</sub>	DC supply current	$V_S = 8 \text{ V}; \text{ R1} = 39 \Omega;$ $T_j = 25 ^{\circ}\text{C}$	-	78	-	mA
$ s_{21} ^2$	insertion power gain	f = 1950 MHz	-	16	-	dB
NF	noise figure	f = 1950 MHz	-	3.3	-	dB
$P_{L1dB}$	load power at 1 dB	f = 850 MHz	-	20	-	dBm
	gain compression	f = 1950 MHz	-	17	-	dBm

# 2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	RF_OUT/BIAS		
2	GND		3————1
3	RF_IN	3 2 1	2 /// sym130

# 3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BGA6489	SC-62	plastic surface-mounted package; collector pad for good heat transfer; 3 leads	SOT89

# 4. Marking

Table 4. Marking codes

Type number	Marking code
BGA6489	4A

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# 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_D$	DC device voltage	on pin 1; RF input AC coupled	-	6	V
Is	DC supply current		-	150	mA
P <sub>tot</sub>	total power dissipation	T <sub>sp</sub> ≤ 70 °C	1] _	800	mW
$T_{stg}$	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
$P_D$	maximum drive power		-	15	dBm

<sup>[1]</sup>  $T_{sp}$  is the temperature at the solder point of the ground lead, pin 2.

# 6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$R_{th(j-sp)}$	thermal resistance from junction to solder point	$T_{sp} \le 70~^{\circ}C$	<u>11</u> 100	K/W

<sup>[1]</sup>  $T_{sp}$  is the temperature at the solder point of the ground lead, pin 2.

# 7. Characteristics

Table 7. Static characteristics

 $V_S = 8 \ V; \ T_j = 25 \ ^{\circ}C; \ R_{bias} = 39 \ \Omega^{[1]}$ 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_D$	DC device voltage	on pin 1; $I_S = 78 \text{ mA}$	-	5.1	-	V
Is	supply current		70	78	86	mΑ

<sup>[1]</sup>  $V_S = DC$  operating supply voltage applied to  $R_{bias}$ ; see Figure 10

### Table 8. Characteristics

 $V_S$  = 8 V;  $I_S$  = 78 mA;  $T_{amb}$  = 25 °C;  $IP3_{(out)}$  tone spacing = 1 MHz;  $P_L$  = 0 dB per tone,  $R_{bias}$  = 39  $\Omega$ ;  $Z_L$  =  $Z_S$  = 50  $\Omega$ ; unless otherwise specified; see <u>Figure 10</u>.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$ s_{21} ^2$	Insertion power gain	f = 850 MHz	-	20	-	dB
		f = 1950 MHz	-	16	-	dB
		f = 2500 MHz	-	15	-	dB
$R_{LIN}$	return losses input	f = 850 MHz	-	14	-	dB
		f = 1950 MHz	-	16	-	dB
		f = 2500 MHz	-	19	-	dB
$R_{LOUT}$	return losses output	f = 850 MHz	-	16	-	dB
		f = 1950 MHz	-	12	-	dB
		f = 2500 MHz	-	10	-	dB

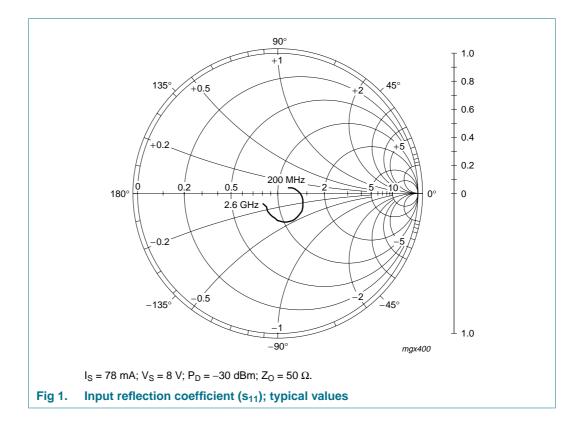
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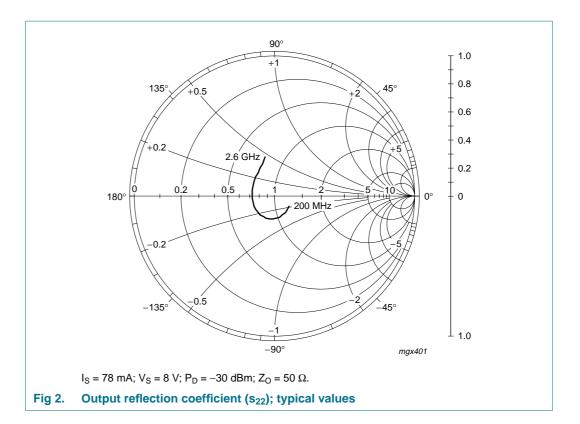
# MMIC wideband medium power amplifier

Table 8. Characteristics ... continued  $V_S = 8 \ V; I_S = 78 \ mA; T_{amb} = 25 \ ^{\circ}C; IP3_{(out)} \ tone \ spacing = 1 \ MHz; P_L = 0 \ dB \ per \ tone, R_{bias} = 39 \ \Omega;$   $Z_L = Z_S = 50 \ \Omega;$  unless otherwise specified; see Figure 10.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
NF	noise figure	f = 850 MHz	-	3.1	-	dB
		f = 1950 MHz	-	3.3	-	dB
		f = 2500 MHz	-	3.4	-	dB
K	stability factor	f = 850 MHz	-	1.2	-	
		f = 2500 MHz	-	1.3	-	
$P_{L1dB}$	load power at 1 dB gain compression	f = 850 MHz	-	20	-	dBm
		f = 1950 MHz	-	17	-	dBm
IP3 <sub>(in)</sub>	input intercept point	f = 850 MHz	-	13	-	dBm
		f = 2500 MHz	-	12	-	dBm
IP3 <sub>(out)</sub>	output intercept point	f = 850 MHz	-	33	-	dBm
		f = 2500 MHz	-	27	-	dBm



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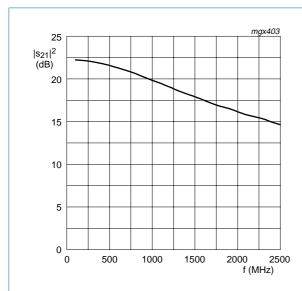
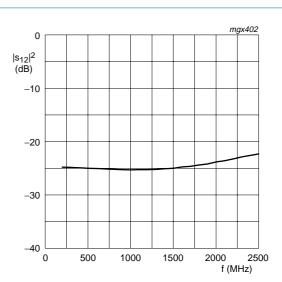


Fig 3. Insertion power gain ( $|s_{21}|^2$ ) as a function of frequency; typical values

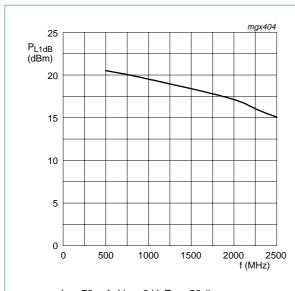
 $I_S$  = 78 mA;  $V_S$  = 8 V;  $P_D$  = -30 dBm;  $Z_O$  = 50  $\Omega$ .



 $I_S$  = 78 mA;  $V_S$  = 8 V;  $P_D$  = –30 dBm;  $Z_O$  = 50  $\Omega.$ 

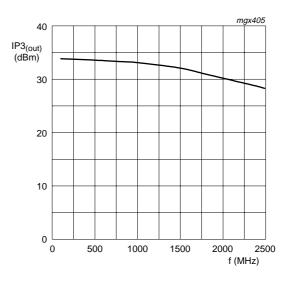
Fig 4. Isolation ( $|s_{12}|^2$ ) as a function of frequency; typical values

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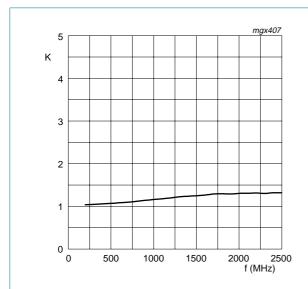
 $I_S$  = 78 mA;  $V_S$  = 8 V;  $Z_O$  = 50  $\Omega.$ 

Fig 5. Load power as a function of frequency; typical values



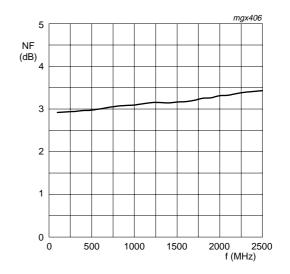
 $I_S$  = 78 mA;  $V_S$  = 8 V;  $Z_O$  = 50  $\Omega$ .

Fig 6. Output intercept as a function of frequency; typical values



 $I_S = 78 \text{ mA}; V_S = 8 \text{ V}; Z_O = 50 \Omega.$ 

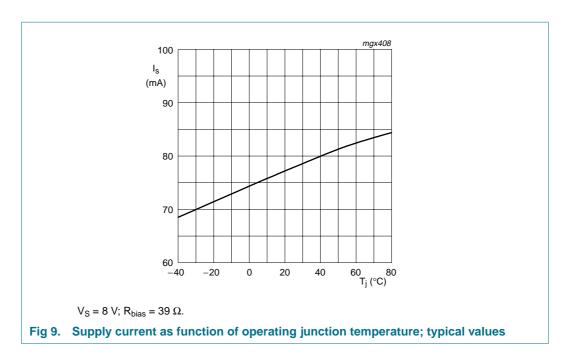
Fig 7. Stability factor as a function of frequency; typical values



 $I_S$  = 78 mA;  $V_S$  = 8 V;  $Z_O$  = 50  $\Omega$ .

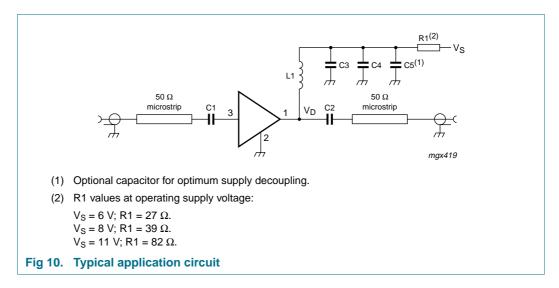
Fig 8. Noise figure as a function of frequency; typical values

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# 8. Application information

Figure 10 shows a typical application circuit for the BGA6489 MMIC. The device is internally matched to 50  $\Omega$  and therefore does not require any external matching. The value of the input and output DC blocking capacitors C1 and C2 depends on the operating frequency; see Table 9. Capacitors C1 and C2 are used in conjunction with L1 and C3 to fine tune the input and output impedance. Capacitor C4 is a supply decoupling capacitor. A 1 μF capacitor (C5) can be added for optimum supply decoupling. The external components should be placed as close as possible to the MMIC. When using via holes, use multiple via holes per pin in order to limit ground path induction. Resistor R1 is a bias resistor providing DC current stability with temperature.



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Table 9. List of components

See Figure 10 for circuit.

Component	Description	Package	Value at operating frequency					
			500 MHz	800 MHz	1950 MHz	2400 MHz	3500 MHz	
C1, C2	multilayer ceramic chip capacitor	0603	220 pF	100 pF	68 pF	56 pF	39 pF	
C3	multilayer ceramic chip capacitor	0603	100 pF	68 pF	22 pF	22 pF	15 pF	
C4	multilayer ceramic chip capacitor	0603	1 nF	1 nF	1 nF	1 nF	1 nF	
C5[1]	electrolytic or tantalum capacitor	0603	1 μF	1 μF	1 μF	1 μF	1 μF	
L1	SMD inductor	0603	68 nH	33 nH	22 nH	18 nH	15 nH	
R1	SMD resistor 0.5 W; $V_S = 8 \text{ V}$	-	$39 \Omega$	$39 \Omega$	$39 \Omega$	$39 \Omega$	39 Ω	

<sup>[1]</sup> Optional.

# 8.1 Scattering parameters

Table 10. Scattering parameters

 $I_S = 78 \text{ mA}; V_S = 8 \text{ V}; P_D = -30 \text{ dBm}; Z_O = 50 \Omega; T_{amb} = 25 ^{\circ}C$ 

f (MHz)	s <sub>11</sub>		s <sub>21</sub>	s <sub>21</sub>		s <sub>12</sub> s <sub>22</sub>		s <sub>22</sub>	
	Magnitude (ratio)	Angle (degree)	Magnitude (ratio)	Angle (degree)	Magnitude (ratio)	Angle (degree)	Magnitude (ratio)	Angle (degree)	
200	0.06	28.11	12.79	164.42	0.06	-0.30	0.12	-22.91	1.1
300	0.09	27.41	12.59	156.85	0.06	-0.39	0.13	-35.38	1.1
400	0.11	21.64	12.31	149.28	0.06	-0.35	0.14	-46.54	1.1
500	0.12	15.28	11.97	141.88	0.06	-0.32	0.14	-57.20	1.1
600	0.14	8.01	11.57	134.79	0.06	0.04	0.15	-61.41	1.1
700	0.16	0.34	11.18	127.97	0.06	0.63	0.16	-76.76	1.1
800	0.17	-7.27	10.75	121.56	0.05	1.57	0.16	-85.75	1.2
900	0.18	-14.78	10.24	115.06	0.05	1.85	0.17	-94.28	1.2
1000	0.19	-22.18	9.80	109.18	0.05	3.16	0.17	-102.4	1.2
1100	0.20	-29.33	9.40	103.40	0.05	4.29	0.17	-110.3	1.2
1200	0.21	-36.41	8.96	98.12	0.05	5.64	0.17	-118.5	1.2
1300	0.21	-42.47	8.53	92.76	0.05	7.03	0.17	-126.7	1.2
1400	0.22	-49.06	8.16	87.50	0.06	7.74	0.17	-134.8	1.2
1500	0.22	-55.46	7.85	82.76	0.06	9.08	0.17	-143.5	1.3
1600	0.22	-61.20	7.51	78.52	0.06	10.76	0.16	-152.7	1.3
1700	0.22	-67.02	7.16	74.16	0.06	11.89	0.16	-161.8	1.3
1800	0.21	-73.40	6.90	69.37	0.06	12.34	0.16	-171.9	1.3
1900	0.21	-78.99	6.69	65.14	0.06	13.16	0.16	177.4	1.3
2000	0.20	-84.54	6.42	61.15	0.06	14.33	0.16	166.81	1.3
2100	0.19	-91.32	6.16	56.80	0.07	14.84	0.17	156.07	1.3
2200	0.18	-97.58	5.99	52.55	0.07	15.05	0.17	145.29	1.3
2300	0.17	-103.60	5.83	49.08	0.07	15.72	0.19	135.65	1.3
2400	0.16	-111.90	5.58	45.43	0.07	15.96	0.20	126.23	1.3
2500	0.14	-120.80	5.39	40.67	0.08	15.27	0.22	117.16	1.3
2600	0.13	-129.80	5.30	36.66	0.08	14.68	0.24	110.35	1.3

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Table 10. Scattering parameters  $I_S = 78$  mA;  $V_S = 8$  V;  $P_D = -30$  dBm;  $Z_O = 50$   $\Omega$ ;  $T_{amb} = 25$  °C

f (MHz)	s <sub>11</sub>	s <sub>21</sub>			s <sub>12</sub>		s <sub>22</sub>		K
	Magnitude (ratio)	Angle (degree)	Magnitude (ratio)	Angle (degree)	Magnitude (ratio)	Angle (degree)	Magnitude (ratio)	Angle (degree)	
2700	0.13	-143.80	5.18	33.88	0.08	15.64	0.28	104.05	1.3
2800	0.12	-154.47	5.08	30.28	0.08	15.56	0.31	97.10	1.3
2900	0.11	-164.40	4.71	22.43	0.09	11.60	0.28	91.75	1.3
3000	0.11	178.65	4.66	18.90	0.09	11.05	0.31	84.80	1.3
3100	0.12	160.01	4.45	18.63	0.10	10.63	0.33	80.37	1.3

## **MMIC** wideband medium power amplifier

# 9. Package outline

Plastic surface-mounted package; collector pad for good heat transfer; 3 leads

SOT89

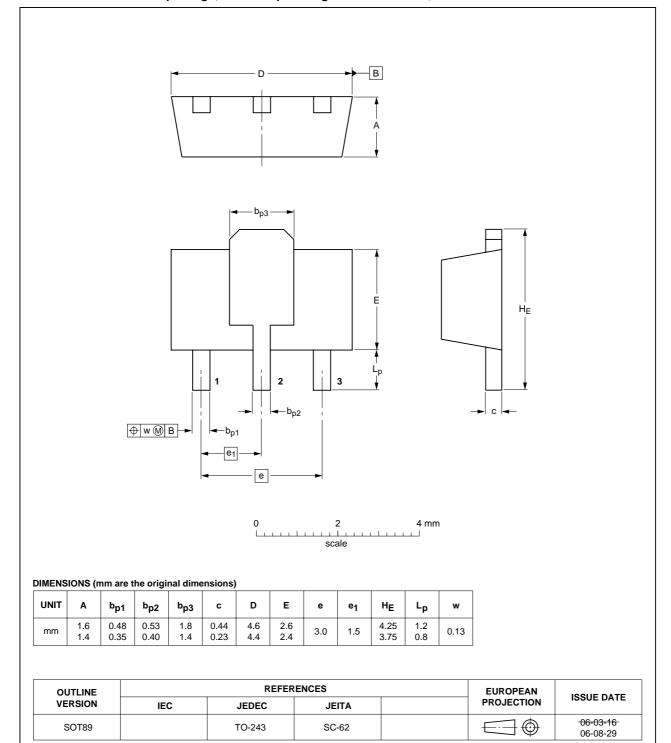


Fig 11. Package outline SOT89 (SC-62)

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# 10. Abbreviations

Table 11. Abbreviations

Acronym	Description
CDPD	Cellular Digital Packet Data
IF	Intermediate Frequency
PCS	Personal Communication Service
SMD	Surface Mount Device
SONET	Synchronous Optical NETwork

# 11. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
BGA6489_2	20090615	Product data sheet	-	BGA6489_1		
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li> </ul>					
	<ul> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>					
	<ul> <li>Changed I<sub>S</sub> from 74 mA to 78 mA throughout.</li> </ul>					
	<ul> <li><u>Table 1</u>: changed symbol V<sub>S</sub> to V<sub>D</sub>.</li> </ul>					
	<ul> <li>Table 5: changed symbol V<sub>S</sub> to V<sub>D</sub> and added "on pin 1;" to Conditions.</li> </ul>					
	<ul> <li><u>Table 7</u>: added row for V<sub>D</sub> DC device voltage.</li> </ul>					
	<ul> <li><u>Section 8</u>: added sentence.</li> </ul>					
	<ul> <li>Table 9: added 39 Ω to all value columns for resistor R1.</li> </ul>					
	<ul> <li><u>Table 9</u>: amended values of C3 and C4.</li> </ul>					
BGA6489_1	20030918	Product data sheet	-	-		

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# 12. Legal information

#### 12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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